

1N4001 THRU 1N4007

VOLTAGE RANGE
CURRENT

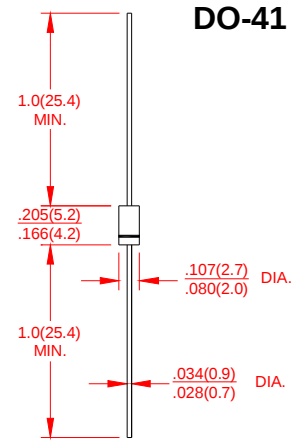
50 to 1000 Volts
1.0 Ampere

FEATURES

- Low coat construction
- Low forward voltage drop
- Low reverse leakage
- High forward surge current capability
- High temperature soldering guaranteed:
260°C/10 secods/.375"(9.5mm)lead length at 5 lbs(2.3kg) tension

MECHANICAL DATA

- Case: Transfer molded plastic
- Epoxy: UL94V-O rate flame retardant
- Polarity: Color band denotes cathode end
- Lead: Plated axial lead, solderable per MIL-STD-202E method 208C
- Mounting position: Any
- Weight: 0.012 ounce, 0.33 grams



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

- Ratings at 25°C ambient temperature unless otherwise specified
- Single Phase, half wave, 60Hz, resistive or inductive load
- For capacitive load derate current by 20%

		SYMBOLS	1N4001	1N4002	1N4003	1N4004	1N4005	1N4006	1N4007	UNIT
Maximum Repetitive Peak Reverse Voltage		V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage		V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage		V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current 0.375”(9.5mm) lead length at T _A = 25 °C		I _(AV)	1.0							Amps
Peak Forward Surge Current 8.3mS single half sine wave superimposed on rated load (JEDEC method)		I _{FSM}	30							Amps
Maximum Instantaneous Forward Voltage @ 1.0A		V _F	1.1							Volts
Maximum DC Reverse Current at Rated DC Blocking Voltage per element	T _A = 25 °C	I _R	5.0							μA
	T _A = 100°C		50							
Maximum Full Load Reverse Current, full cycle average 0.375”(9.5mm)lead length at T _L =75 °C		I _{R(AV)}	30							μA
Typical Junction Capacitance (Note 1)		C _J	13							pF
Typical Thermal Resistance (Note 2)		R _{θJA}	50							°C/W
Operating Junction Temperature Range		T _J	-55 to +150							°C
Storage Temperature Range		T _{STG}	-55 to +150							°C

Notes:

1. Measured at 1.0MHz and Applied Reverse Voltage of 4.0V DC.
2. Thermal Resistance from junction to terminal 6.0mm² copper pads to each terminal.
3. The chip size is 40mi l × 40mi l

RATING AND CHARACTERISTIC CURVES 1N4001 Thru 1N4007

FIG.1-TYPICAL FORWARD CURRENT
DERATING CURVE

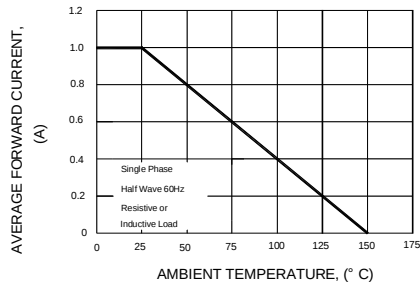


FIG.2-MAXIMUM NON-REPETITIVE PEAK
FORWARD SURGE CURRENT

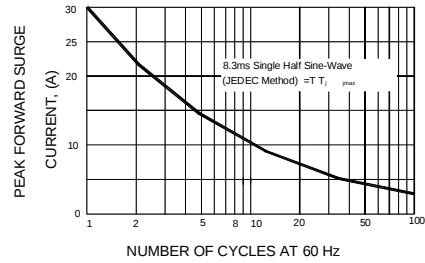


FIG.3-TYPICAL INSTANTANEOUS
FORWARD CHARACTERISTICS

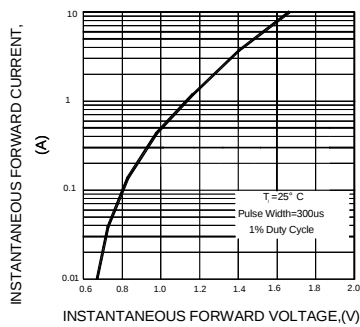


FIG.4-TYPICAL REVERSE
CHARACTERISTICS

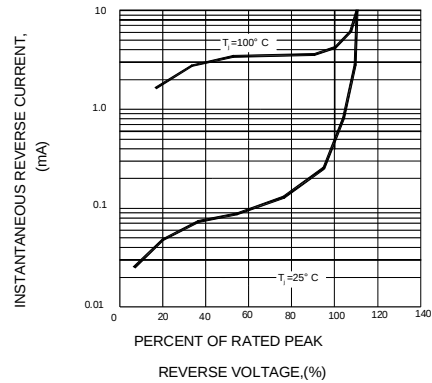


FIG.5-TYPICAL JUNCTION CAPACITANCE

